

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Compact fluorescent lamps (CFLs)
- SMPS for battery charger

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The STBV45G and STBV45G-AP are supplied using halogen-free molding compound.

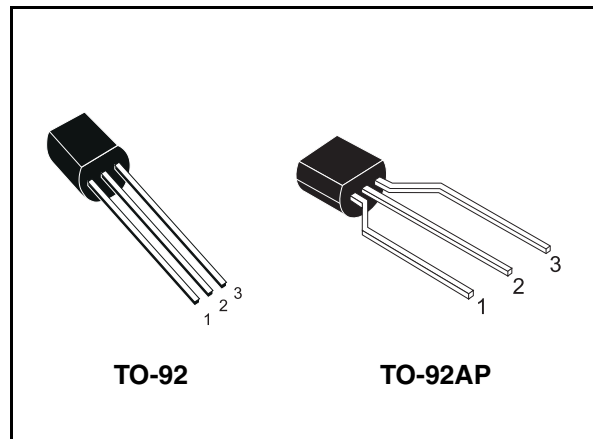


Figure 1. Internal schematic diagram

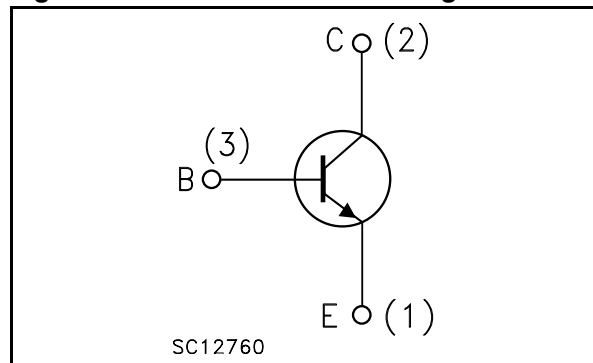


Table 1. Device summary

Order codes	Marking	Package	Packaging
STBV45	BV45	TO-92	Bulk
STBV45G	BV45G	TO-92	Bulk
STBV45-AP	BV45	TO-92AP	Ammopack
STBV45G-AP	BV45G	TO-92AP	Ammopack

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	9	V
I_C	Collector current	0.75	A
I_{CM}	Collector peak current ($t_P < 5$ ms)	1.5	A
I_B	Base current	0.4	A
I_{BM}	Base peak current ($t_P < 5$ ms)	0.75	A
P_{TOT}	Total dissipation at $T_C = 25$ °C	0.95	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case max	131.6	°C/W

2 Electrical characteristics

($T_{\text{case}} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = 700\text{ V}$			250	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 9\text{ V}$			1	mA
$V_{\text{CEQ(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 1\text{ mA}$	400			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 0.2\text{ A}$ $I_{\text{B}} = 40\text{ mA}$		0.2	0.5	V
		$I_{\text{C}} = 0.3\text{ A}$ $I_{\text{B}} = 75\text{ mA}$		0.3	1	V
		$I_{\text{C}} = 0.4\text{ A}$ $I_{\text{B}} = 135\text{ mA}$		0.4	1.5	V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 0.2\text{ A}$ $I_{\text{B}} = 40\text{ mA}$			1	V
		$I_{\text{C}} = 0.3\text{ A}$ $I_{\text{B}} = 75\text{ mA}$			1.2	V
h_{FE}	DC current gain	$I_{\text{C}} = 0.5\text{ mA}$ $V_{\text{CE}} = 2\text{ V}$	12			
		$I_{\text{C}} = 0.2\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	10		30	
		$I_{\text{C}} = 0.4\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	5		20	
t_{f}	Inductive load Fall time	$I_{\text{C}} = 0.2\text{ A}$ $V_{\text{clamp}} = 300\text{ V}$ $I_{\text{B1}} = -I_{\text{B2}} = 40\text{ mA}$ $L = 3\text{ mH}$ <i>Figure 8.</i>		0.3		μs

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

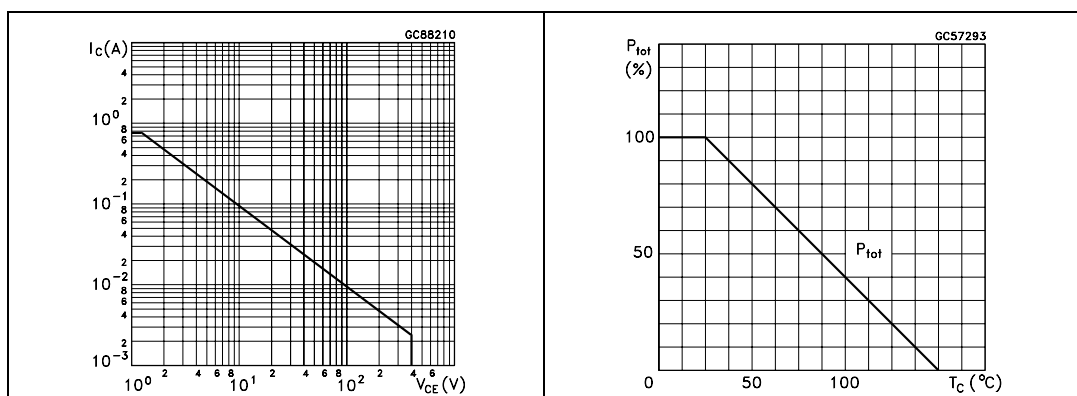


Figure 4. DC current gain

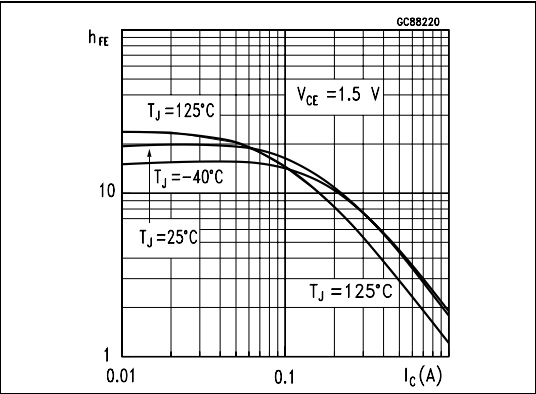


Figure 5. DC current gain

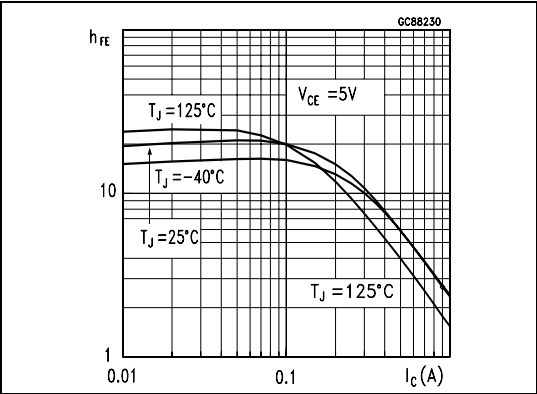


Figure 6. Collector-emitter saturation voltage

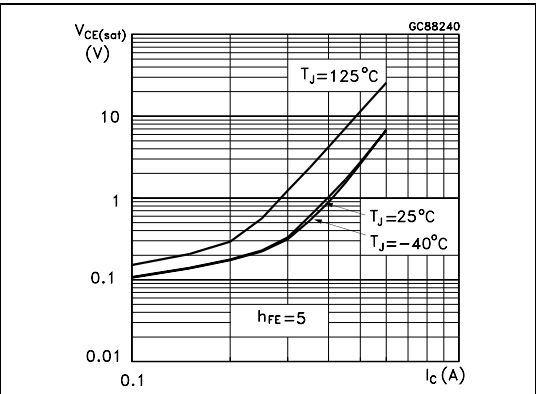
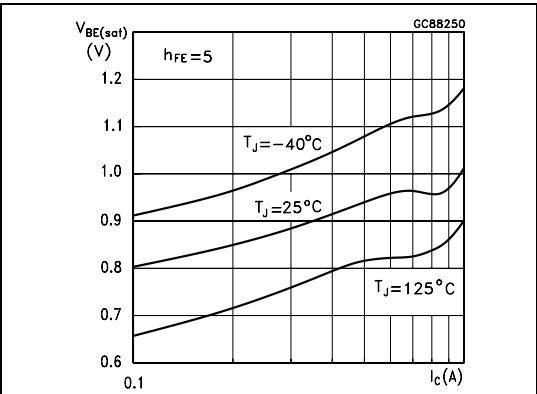
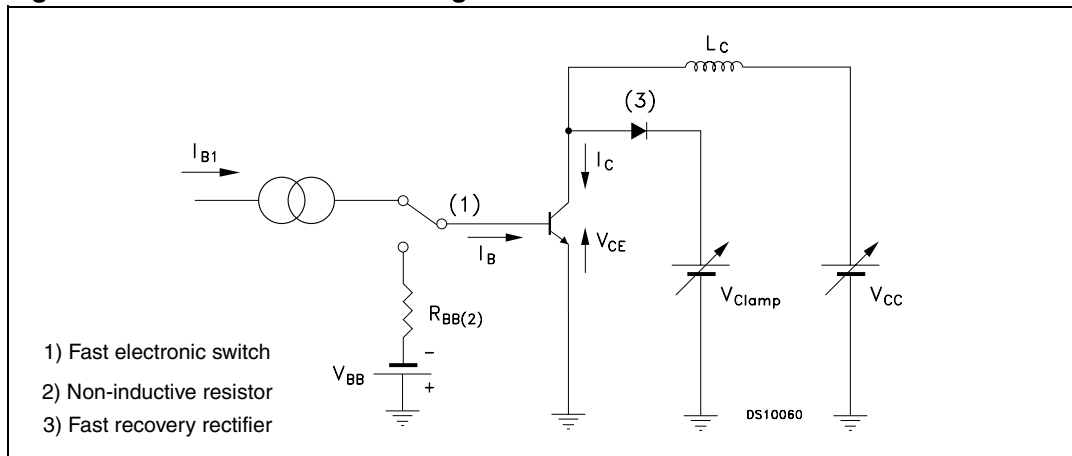


Figure 7. Base-emitter saturation voltage



2.2 Test circuit

Figure 8. Inductive load switching test circuit

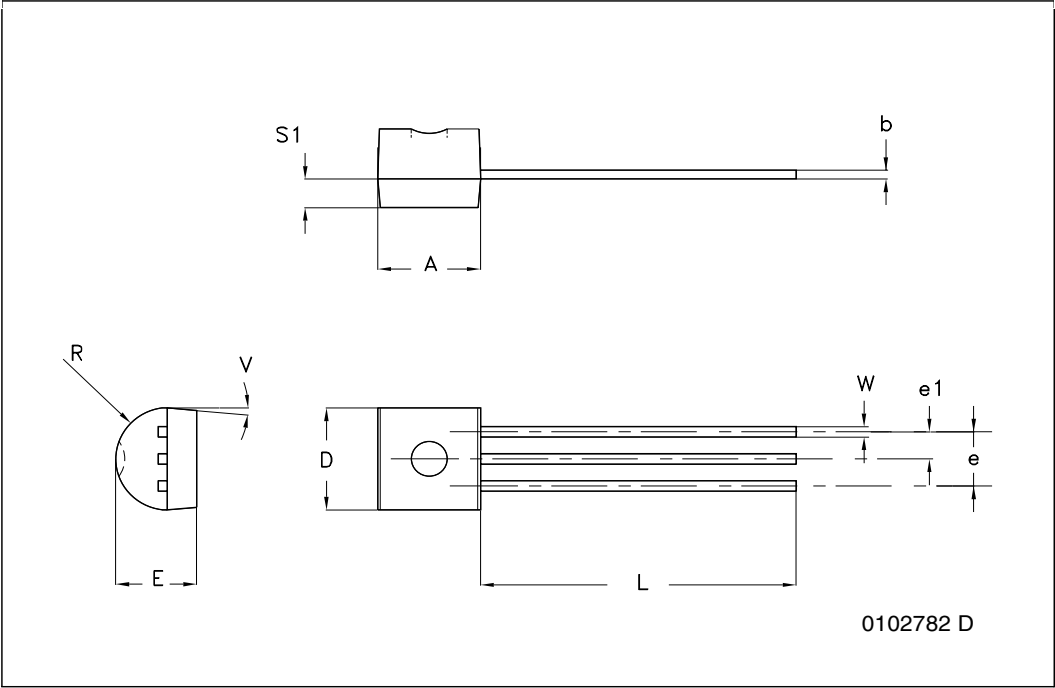


3 **Package mechanical data**

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

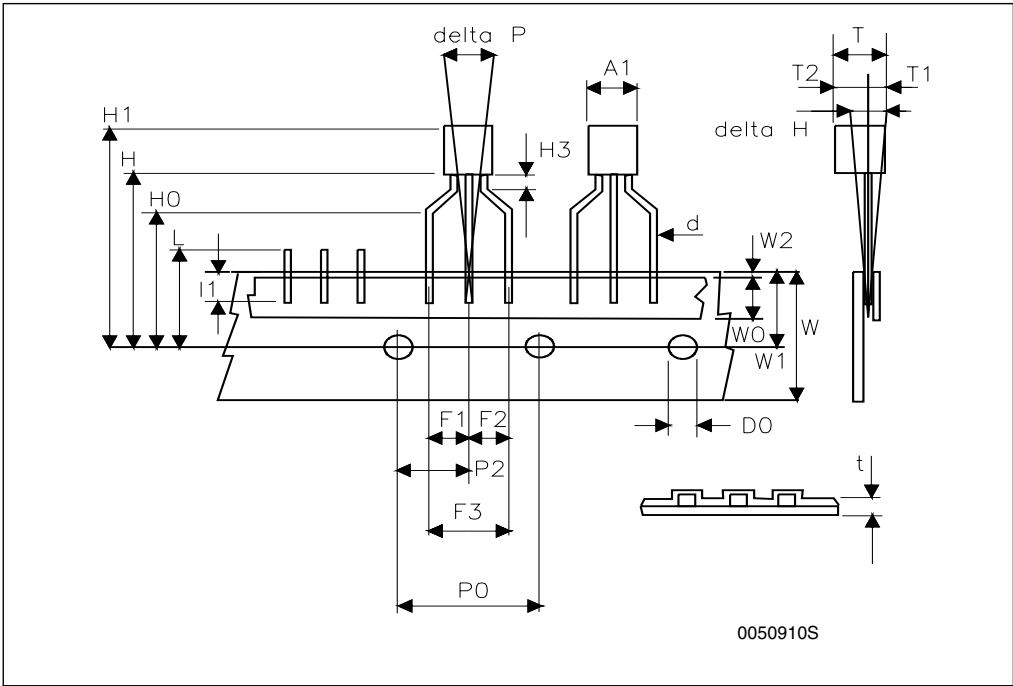
TO-92 bulk shipment mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	



TO-92 ammpack shipment (suffix"-AP") mechanical data

Dim.	mm		
	Min	Typ	Max
A1			4.80
T			3.80
T1			1.60
T2			2.30
d			0.48
P0	12.50	12.70	12.90
P2	5.65	6.35	7.05
F1,F2	2.44	2.54	2.94
F3	4.98	5.08	5.48
delta H	-2.00		2.00
W	17.50	18.00	19.00
W0	5.70	6.00	6.30
W1	8.50	9.00	9.25
W2			0.50
H	18.50		20.50
H3	0.5	1	1.5
H0	15.50	16.00	16.50
H1			25.00
D0	3.80	4.00	4.20
t			0.90
L			11.00
l1	3.00		
delta P	-1.00		1.00



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
13-Jul-2004	4	
03-Jul-2008	5	Added halogen-free molding compound package.
22-Oct-2008	6	Updated Table 2 on page 2 and Table 4 on page 3

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